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TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

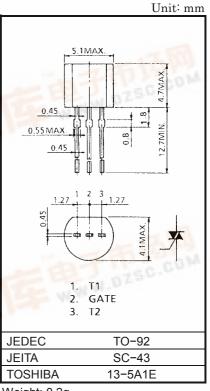
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AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : VDRM = 800V
- R.M.S. On–State Current : IT (RMS) = 1A

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off-State Voltage	V _{DRM}	800	V	
R.M.S. On-State Current (Full Sine Waveform Tc = 74°C)	I _{T (RMS)}	1.0	А	
Peak One Cycle Surge On-State Current (Non-Repetitive)	I	8 (50Hz)	•	
	ITSM	8.8 (60Hz)	A	
I ² t Limit Value (t = 1~10ms)	l ² t	0.32	A ² s	
Peak Gate Power Dissipation	P _{GM}	1	W	
Average Gate Power Dissipation	P _G (AV)	0.1	W	
Peak Gate Voltage	V _{GM}	6	V	
Peak Gate Current	I _{GM}	0.5	А	
Junction Temperature	Tj	-40~125	°C	
Storage Temperature Range	T _{stg}	-40~125	°C	



Weight: 0.2g



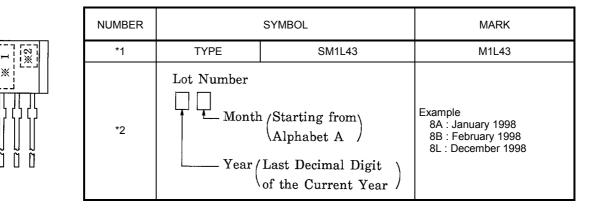
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ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} = 800V		—	_	10	μA
Gate Trigger Voltage	Ι	V _{GT}	V _D =12V, R _L = 20Ω	T2 (+) , Gate (+)	_	_	1.5	V
	П			T2 (+) , Gate (−)	_	_	1.5	
	Ш			T2 (−) , Gate (−)	_	_	1.5	
Gate Trigger Current	I	I _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)	_	_	10	mA
	П			T2 (+) , Gate (−)	_	_	10	
	Ш			T2 (−) , Gate (−)	_	_	10	
Peak On-State Voltage		V _{TM}	I _{TM} = 1.5A		_	_	1.5	V
Gate Non-Trigger Voltage VG		V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V
Holding Current I		Ι _Η	V _D = 12V, I _{TM} = 1A		_	_	10	mA
Thermal Resistance R _{th (j} -		R _{th (j−c)}	Junction to Case, AC		_	_	40	°C/W
Thermal Resistance F		R _{th (j−a)}	Junction to Ambient, AC		—	_	180	°C/W

MARKING

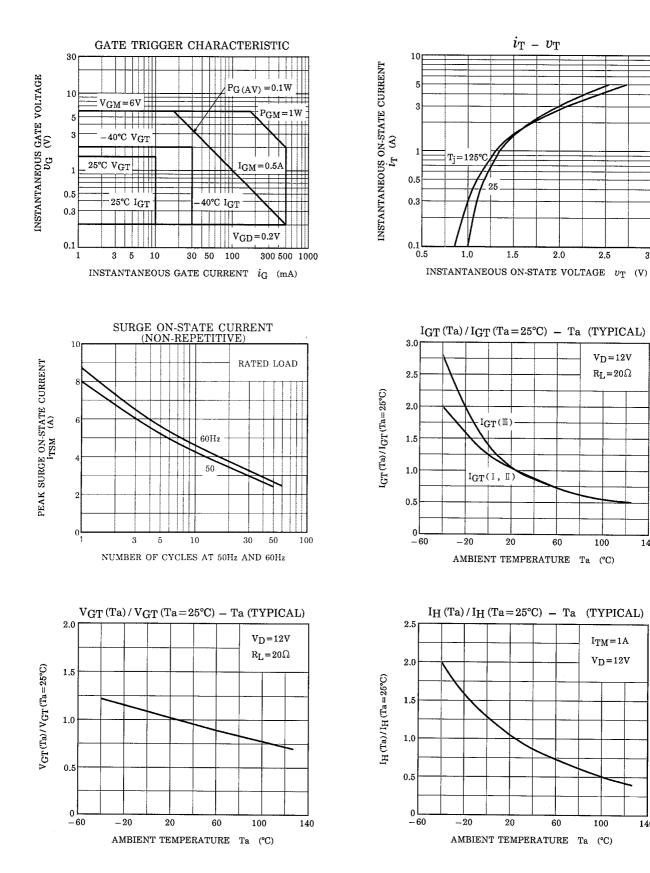


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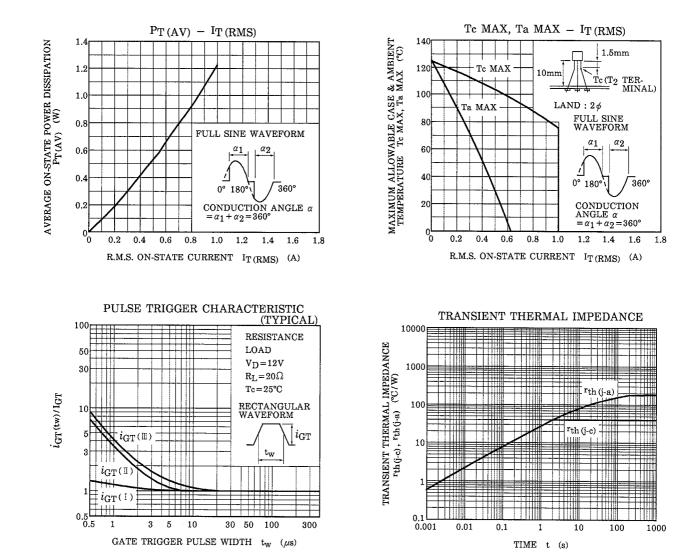




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